## Claims

- An epoxy resin for sealing photosemiconductor, comprising
- (A) a bisphenol-type epoxy resin represented by the following formula (1)

(1)

(wherein,  $R_1$ s represent hydrogen atom, a C1 - C8 alkyl group, a halogen atom, which may be the same or different;  $R_2$ s represent hydrogen atom, a C1 - C5 alkyl group, a halogen-substituted (C1 - C5) alkyl group or phenyl group, which may be the same or different; n represents an integer), where the ratio of the total content of such bisphenol-type lower molecular epoxy resins with n = 0, 1 or 2 is 10% by weight or more based on the whole resin; (B) a terpene backbone-containing polyvalent phenol curing agent prepared by adding two molecules of phenols to one molecule of a cyclic terpene compound;

- (C) a curing-promoting agent;
- (D) at least one resin selected from the group consisting of epoxy resins except for the component (A) and novolak resins as curing agents.
  - 2. The epoxy resin composition for sealing

4

photosemiconductor according to claim 1 containing epoxy resins except for the component A, where the ratio of the total content of bisphenol-type lower molecular epoxy resins with n=0, 1 or 2 in the formula (1) is 10% by weight or more based on the whole epoxy resin.

- 3. The epoxy resin composition for sealing photosemiconductor according to claim 1, where the ratio of the total content of the bisphenol-type lower molecular epoxy resins in the epoxy resin of the component (A) is 15 to 50% by weight based on the whole component (A).
- 4. The epoxy resin composition for sealing photosemiconductor according to claim 1 or 3 containing epoxy resins except for the epoxy resin of the component (A) as the component (D) at 20 to 90% by weight and the epoxy resin of the component (A) at 10 to 80%, by weight based on the whole epoxy resin.
- 5. The epoxy resin composition for sealing photosemiconductor according to claim 4, where the epoxy resins except for the component (A) are biphenyl backbone-containing phenol novolak resins.
- 6. The epoxy resin composition for sealing photosemiconductor according to claim 1, where the component (A) is bisphenol type-A and/or bisphenol type-F epoxy resin.
- 7. The epoxy resin composition for sealing photosemiconductor according to claim 1, where the terpene

backbone-containing polyvalent phenol curing agent as the component (B) is of a bifunctional type.

- 8. A photosemiconductor device sealed with a cured material of an epoxy resin composition according to any one of claims 1 to 7.
- 9. A method for producing sealed photosemiconductor device characterized by sealing an photosemiconductor device with an epoxy resin composition according to any one of claims 1 to 7.
- 10. The epoxy resin composition according to any one of claims 1 to 7, where the cured product of the resin composition has a glass transition temperature of 105°C or more and the ratio of the peeled area of the cured resin after absorption of moisture in the photosemiconductor device sealed with the said cured product is 60% or less.